- State-of-the-Art Advanced BiCMOS
 Technology (ABT) Widebus™ Design for
 2.5-V and 3.3-V Operation and Low Static
 Power Dissipation
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 2.3-V to 3.6-V V_{CC})
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Power Off Disables Outputs, Permitting Live Insertion
- High-Impedance State During Power Up and Power Down Prevents Driver Conflict
- Uses Bus Hold on Data Inputs in Place of External Pullup/Pulldown Resistors to Prevent the Bus From Floating
- Output Ports Have Equivalent 30-Ω Series Resistors, So No External Resistors Are Required
- Auto3-State Eliminates Bus Current Loading When Output Exceeds V_{CC} + 0.5 V
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model; and Exceeds 1000 V Using Charged-Device Model, Robotic Method
- Flow-Through Architecture Facilitates
 Printed Circuit Board Layout
- Distributed V_{CC} and GND Pin Configuration Minimizes High-Speed Switching Noise
- Package Options Include Plastic Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), Thin Very Small-Outline (DGV) Packages, and 380-mil Fine-Pitch Ceramic Flat (WD) Package

NOTE: For order entry:

The DGG package is abbreviated to G, and the DGV package is abbreviated to V.

description

The 'ALVTH162827 devices are 20-bit buffers/line drivers designed for 2.5-V or 3.3-V V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Widebus is a trademark of Texas Instruments Incorporated.

SN54ALVTH162827 . . . WD PACKAGE SN74ALVTH162827 . . . DGG, DGV, OR DL PACKAGE (TOP VIEW)

1				
10E1	1	\cup	56	10E2
1Y1	2		55	1A1
1Y2	3		54	1A2
GND[4		53	GND
1Y3[5		52] 1A3
1Y4[6		51] 1A4
v _{cc} [7		50] v _{cc}
1Y5[8		49] 1A5
1Y6[9		48] 1A6
1Y7[10		47] 1A7
GND[11		46	GND
1Y8[12		45] 1A8
1Y9[13		44] 1A9
1Y10[14		43] 1A10
2Y1[15		42] 2A1
2Y2[16		41] 2A2
2Y3[17		40	2A3
GND[18		39	GND
2Y4[19		38] 2A4
2Y5[20		37] 2A5
2Y6	21		36	2A6
V _{CC}	22		35	□ v _{cc}
2Y7	23		34	2A7
2Y8	24		33	2A8
GND [25		32	GND
2Y9	26		31	2A9
2Y10	27		30	2 <u>A10</u>
20E1	28		29	20E2
	_			,



description (continued)

The devices are composed of two 10-bit sections with separate output-enable signals. For either 10-bit buffer section, the two output-enable (1OE1 and 1OE2, or 2OE1 and 2OE2) inputs must be low for the corresponding Y outputs to be active. If either output-enable input is high, the outputs of that 10-bit buffer section are in the high-impedance state.

When V_{CC} is between 0 and 1.2 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.2 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

All outputs are designed to sink up to 12 mA, and include equivalent 30- Ω resistors to reduce overshoot and undershoot.

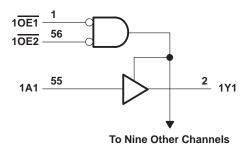
Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

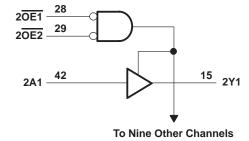
The SN54ALVTH162827 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ALVTH162827 is characterized for operation from –40°C to 85°C.

FUNCTION TABLE (each 10-bit section)

	INPUTS		OUTPUT
OE1	OE2	Α	Y
L	L	L	L
L	L	Н	Н
Н	X	Χ	Z
Х	Н	Χ	Z

logic diagram (positive logic)







absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 4.6 V
Input voltage range, V _I (see Note 1)	0.5 V to 7 V
Voltage range applied to any output in the high-impedance	
or power-off state, V _O (see Note 1)	0.5 V to 7 V
Voltage range applied to any output in the high state, V _O (see Note 1)	0.5 V to 7 V
Output current in the low state, I _O : SN54ALVTH162827	96 mA
SN74ALVTH162827	128 mA
Output current in the high state, IO: SN54ALVTH162827	–48 mA
SN74ALVTH162827	–64 mA
Input clamp current, I _{IK} (V _I < 0)	–50 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Package thermal impedance, θ _{JA} (see Note 2): DGG package	81°C/W
DGV package	86°C/W
DL package	74°C/W
Storage temperature range, T _{stq}	. −65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions, V_{CC} = 2.5 V \pm 0.2 V (see Note 3)

			SN54A	LVTH16	2827	SN74A	LVTH16	2827	UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Vcc	Supply voltage		2.3		2.7	2.3		2.7	V
VIH	High-level input voltage		1.7		7	1.7			V
V _{IL}	Low-level input voltage			Š	0.7			0.7	V
VI	Input voltage		0	Vcc	5.5	0	Vcc	5.5	V
loн	High-level output current			1	-6			-8	mA
loL	Low-level output current			3	8			12	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	0	7	10			10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate		200			200			μs/V
TA	Operating free-air temperature		-55		125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

SN54ALVTH162827, SN74ALVTH162827 2.5-V/3.3-V 20-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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recommended operating conditions, V_{CC} = 3.3 V \pm 0.3 V (see Note 3)

			SN54A	LVTH16	2827	SN74A	LVTH16	2827	UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Vcc	Supply voltage		3		3.6	3		3.6	V
VIH	High-level input voltage		2		7	2			V
V _{IL}	Low-level input voltage			Š	0.8			0.8	V
VI	Input voltage		0	Vcc	5.5	0	VCC	5.5	V
IOH	High-level output current			1	-8			-12	mA
loL	Low-level output current			3	8			12	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	,O,	3	10			10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate		200			200			μs/V
TA	Operating free-air temperature		-55		125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted)

D	PARAMETER TEST CONDITION		ONDITIONS	SN54A	ALVTH16	62827	SN74	ALVTH16	62827	UNIT
Ρ/	ARAWETER	1251 C	UNDITIONS	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNII
٧ıK		$V_{CC} = 2.3 \text{ V},$	I _I = -18 mA			-1.2			-1.2	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	I _{OH} = -100 μA	V _{CC} -0.	2		V _{CC} -0	.2		
VOH		V _{CC} = 2.3 V	$I_{OH} = -6 \text{ mA}$	1.7	1.7					V
		VCC = 2.3 V	$I_{OH} = -8 \text{ mA}$				1.7			
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	$I_{OL} = 100 \mu A$			0.2			0.2	
VOL		V _{CC} = 2.3 V	I _{OL} = 8 mA			0.7				V
	_	VCC = 2.3 V	I _{OL} = 12 mA						0.7	
	Control inputs	$V_{CC} = 2.7 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1	
	Control inputs	$V_{CC} = 0 \text{ or } 2.7 \text{ V},$	V _I = 5.5 V			10			10	
IJ			V _I = 5.5 V			10			10	μΑ
	Data inputs	$V_{CC} = 2.7 \text{ V}$	VI = VCC			\$ 1			1	
			V _I = 0		3	- 5			– 5	
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V		Ph				±100	μΑ
I _{BHL} ‡		$V_{CC} = 2.3 \text{ V},$	$V_{I} = 0.7 \ V$		115			115		μΑ
I _{BHH} §	}	$V_{CC} = 2.3 \text{ V},$	V _I = 1.7 V		3 –10			-10		μΑ
IBHLO	,¶	$V_{CC} = 2.7 \text{ V},$	$V_I = 0$ to V_{CC}	300	5		300			μΑ
Івнно) [#]	$V_{CC} = 2.7 \text{ V},$	$V_I = 0$ to V_{CC}	-300			-300			μΑ
ΙΕΧ		$V_{CC} = 2.3 \text{ V},$	V _O = 5.5 V			125			125	μΑ
I _{OZ(PI}	U/PD) [☆]	$V_{CC} \le 1.2 \text{ V}, V_{O} = \frac{0.5}{\text{OE}} \text{ V}$ V _I = GND or V _{CC} , $\overline{\text{OE}}$ =	/ to V _{CC} , : don't care			±100			±100	μΑ
lozh		V _{CC} = 2.7 V	V _O = 2.3 V, V _I = 0.7 V or 1.7 V			5			5	μΑ
lozL		V _{CC} = 2.7 V	V _O = 0.5 V, V _I = 0.7 V or 1.7 V			- 5			-5	μΑ
		V _{CC} = 2.7 V,	Outputs high		0.04	0.1		0.04	0.1	
ICC		$I_{O} = 0$,	Outputs low		2.3	5		2.3	5	mA
		$V_I = V_{CC}$ or GND	Outputs disabled		0.04	0.1		0.04	0.1	
Ci		V _{CC} = 2.5 V,	V _I = 2.5 V or 0		3.5			3.5		pF
Co		V _{CC} = 2.5 V,	V _O = 2.5 V or 0		6			6		pF

[†] All typical values are at $V_{CC} = 2.5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



[‡] The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

[§] The bus-hold circuit can source at least the minimum high sustaining current at VIH min. IBHH should be measured after raising VIN to VCC and then lowering it to VIH min.

[¶] An external driver must source at least IBHLO to switch this node from low to high.

[#]An external driver must sink at least IBHHO to switch this node from high to low.

 $[\]parallel$ Current into an output in the high state when $V_O > V_{CC}$

^{*}High-impedance state during power up or power down

SN54ALVTH162827, SN74ALVTH162827 2.5-V/3.3-V 20-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted)

DA	DAMETER	TEST O	ONDITIONS	SN54A	LVTH16	52827	SN74	ALVTH16	52827	UNIT
PA	RAMETER	IESI C	ONDITIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNII
VIK		V _{CC} = 3 V,	I _I = -18 mA			-1.2			-1.2	V
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OH} = -100 μA	V _{CC} -0.	2		V _{CC} -0	.2		
Vон		V _{CC} = 3 V	$I_{OH} = -8 \text{ mA}$	2						V
		$I_{OH} = -12 \text{ mA}$					2			
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OL} = 100 μA			0.2			0.2	
VOL		V _{CC} = 3 V	$I_{OL} = 8 \text{ mA}$			0.8				V
		VCC = 3 V	$I_{OL} = 12 \text{ mA}$						0.8	
	Control inputs	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1	
	Control inputs	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V _I = 5.5 V			10			10	
Ч			V _I = 5.5 V			10			10	μΑ
	Data inputs	V _{CC} = 3.6 V	$\Lambda^{I} = \Lambda^{CC}$			1			1	
			V _I = 0			√ –5			– 5	
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V		À				±100	μΑ
I _{BHL} ‡		$V_{CC} = 3 V$,	V _I = 0.8 V	75	St.		75			μΑ
I _{BHH} §		$V_{CC} = 3 V$,	V _I = 2 V	-75	5		-75			μΑ
IBHLO	П	$V_{CC} = 3.6 \text{ V},$	$V_I = 0$ to V_{CC}	500	3		500			μΑ
Івнно ^і	#	$V_{CC} = 3.6 \text{ V},$	$V_I = 0$ to V_{CC}	-500)		-500			μΑ
_{IEX}		V _{CC} = 3 V,	V _O = 5.5 V	Q		125			125	μΑ
loz(PU	J/PD)☆	$V_{CC} \le 1.2 \text{ V}, V_{O} = \underline{0.5} \text{ V}$ $V_{I} = \text{GND or } V_{CC}, \overline{OE} = \underline{0.5} \text{ V}$	V to V _{CC} , = don't care			±100			±100	μΑ
lozh		V _{CC} = 3.6 V	V _O = 3 V, V _I = 0.8 V or 2 V			5			5	μА
lozL		V _{CC} = 3.6 V	V _O = 0.5 V, V _I = 0.8 V or 2 V			- 5			-5	μА
		V _{CC} = 3.6 V,	Outputs high		0.07	0.1		0.07	0.1	
Icc		$I_{O} = 0$,	Outputs low		3.2	5.5		3.2	5.5	mA
		$V_I = V_{CC}$ or GND	Outputs disabled		0.07	0.1		0.07	0.1	
∆lcc□	$V_{CC} = 3 \text{ V to } 3.6 \text{ V, One i}$ Other inputs at V_{CC} or G					0.4			0.4	mA
Ci		V _{CC} = 3.3 V,	V _I = 3.3 V or 0		3.5			3.5		pF
Со		V _{CC} = 3.3 V,	V _O = 3.3 V or 0		6			6		pF

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



[‡]The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL}should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

[§] The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to V_{IH} min.

 $[\]P$ An external driver must source at least $I_{\mbox{\footnotesize{BHLO}}}$ to switch this node from low to high.

[#] An external driver must sink at least I_{BHHO} to switch this node from high to low.

 $[\]parallel$ Current into an output in the high state when $\vee_{O} > \vee_{CC}$

[★]High-impedance state during power up or power down

[□]This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

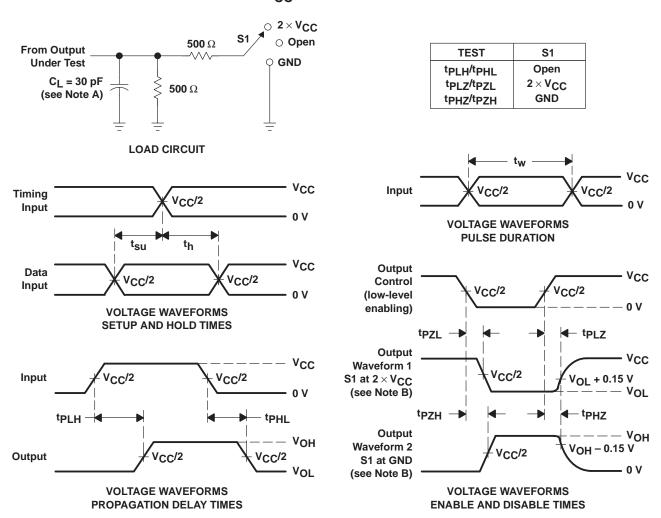
switching characteristics over recommended operating free-air temperature range, C_L = 30 pF, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	SN54ALVT	H162827	SN74ALVTI	1162827	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	۸		1.7	4.1	1.7	4.1	ns
^t PHL	А	ı	1.6	4	1.6	4	115
^t PZH	ŌĒ		2.1	4.8	2.1	4.8	ns
^t PZL	OE	1	1.9	4.8	1.9	4.8	115
^t PHZ	ŌĒ		2.4	6	2.4	6	ns
t _{PLZ}	OE	'	0 1.7	5	1.7	5	115

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	то	SN54ALVTH162827	SN74ALVT	SN74ALVTH162827		
PARAWETER	(INPUT)	(OUTPUT)	MIN MAX	MIN	MAX	UNIT	
tplH	۸	V	1 43.9	1	3.9	ns	
^t PHL	A	ı	1.5 🚜 3.7	1.5	3.7	115	
^t PZH	ŌĒ	V	1 5.6	1	5.6	ns	
^t PZL	OE	ı	1.7 4.1	1.7	4.1	115	
^t PHZ	ŌĒ	v	3.6 6.3	3.6	6.3	ns	
^t PLZ	OE .	,	1.7 5.1	1.7	5.1	113	

PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



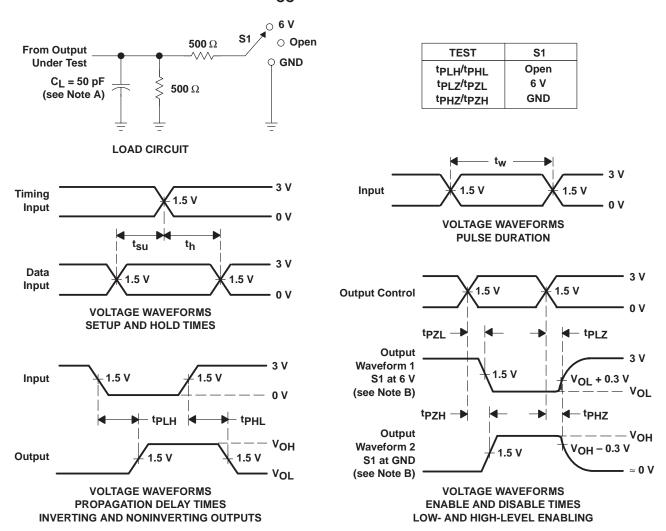
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq 2$ ns. $t_f \leq 2$ ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform22 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50~\Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms



PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74ALVTH162827DL	ACTIVE	SSOP	DL	56	20	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVTH162827	Samples
SN74ALVTH162827GR	ACTIVE	TSSOP	DGG	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVTH162827	Samples
SN74ALVTH162827VR	ACTIVE	TVSOP	DGV	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VT2827	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.



PACKAGE OPTION ADDENDUM

10-Dec-2020

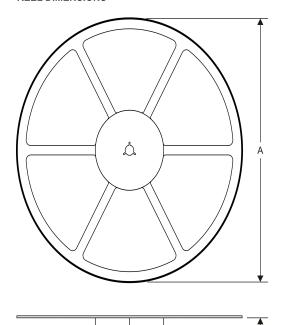
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALVTH162827GR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1
SN74ALVTH162827VR	TVSOP	DGV	56	2000	330.0	24.4	6.8	11.7	1.6	12.0	24.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALVTH162827GR	TSSOP	DGG	56	2000	367.0	367.0	45.0
SN74ALVTH162827VR	TVSOP	DGV	56	2000	367.0	367.0	45.0

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



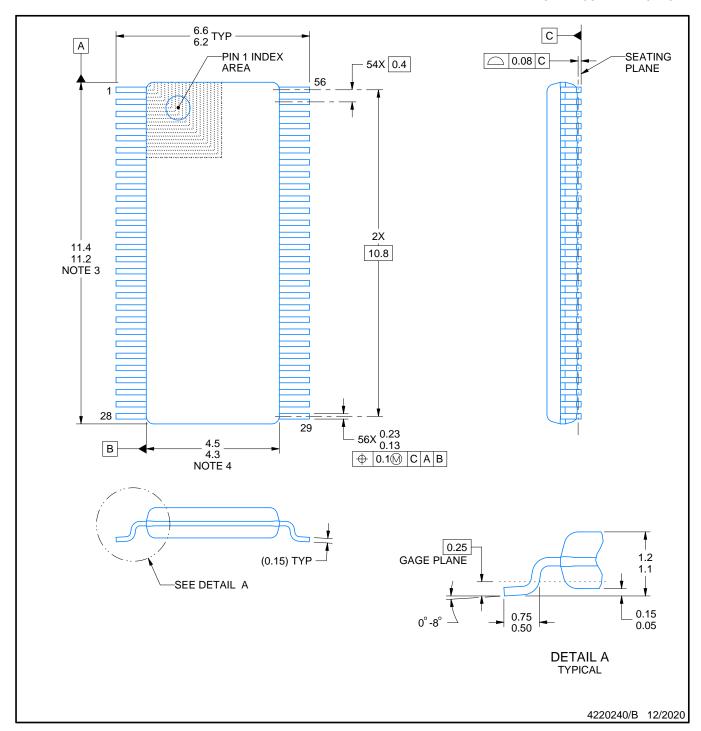
NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194





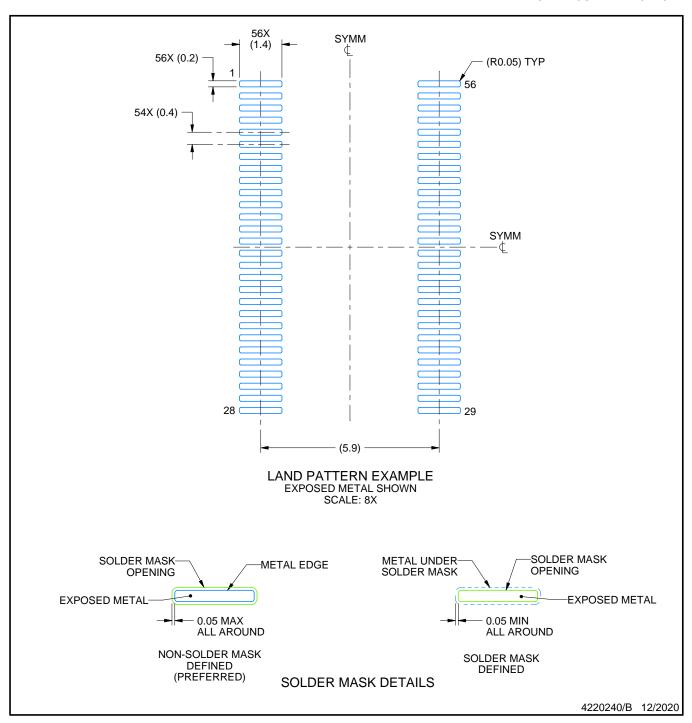
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-194.



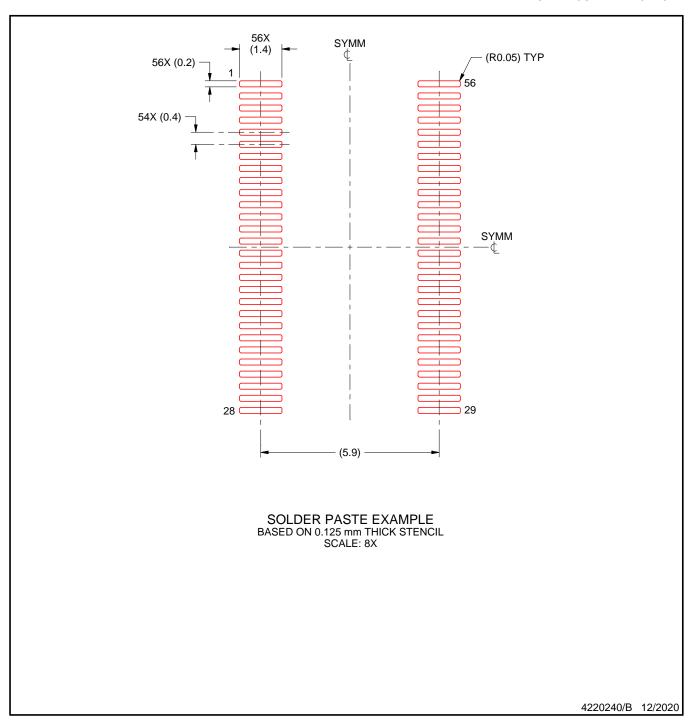


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DL (R-PDSO-G56)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-153.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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